

Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- *Low Power Loss & High efficiency.
- * 150 Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory

Flammability Classification 94V-O

- * ESD: 8KV(Min.) Human-Body Model
- * In compliance with EU RoHs 2002/95/EC directives



MAXIMUM RATINGS

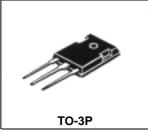
Characteristic	Symbol		11!1					
		30	35	40	45	50	60	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	30	35	40	45	50	60	٧
RMS Reverse Voltage	V _{R(RMS)}	21	25	28	32	35	42	V
Average Rectifier Forward Current Per diodes Total Device (Rated V _R), T _C =125	I _{F(AV)}	7.5 15				Α		
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	15			Α			
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I _{FSM}	200			Α			
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150						

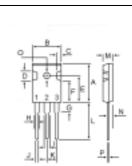
ELECTRIAL CHARACTERISTICS

ELECTRIAL CHARACTERIOTICS								
Characteristic	Symbol	S15D						l lmi4
		30	35	40	45	50	60	Unit
Maximum Instantaneous Forward Voltage ($I_F = 7.5 \text{ Amp } T_C = 25$) ($I_F = 7.5 \text{ Amp } T_C = 100$)	V _F	0.55 0.48			0.65 0.56		V	
Typical Thermal Resistance junction to case	R _{θ j-c}	3.8					/w	
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25$) (Rated DC Voltage, $T_C = 125$)	I _R	0.5 20			mA			

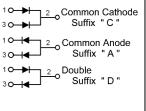
SCHOTTKY BARRIER RECTIFIERS

15 AMPERES 30-60 VOLTS

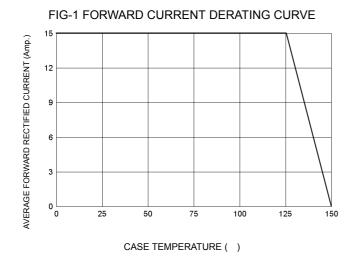


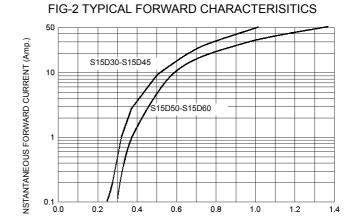


DIM	MILLIMETERS				
	MIN	MAX			
Α	20.63	22.38			
В	15.38	16.20			
С	1.90	2.70			
D	5.10	6.10			
Ε	14.81	15.22			
F	11.72	12.84			
G	4.20	4.50			
Н	1.82	2.46			
1	2.92	3.23			
J	0.89	1.53			
K	5.26	5.66			
L	18.50	21.50			
M	4.68	5.36			
Ν	2.40	2.80			
0	3.25	3.65			
Р	0.55	0.70			



S15D30 Thru S15D60





0.6

FORWARD VOLTAGE (Volts)

8.0

1.0

1.2

0.2



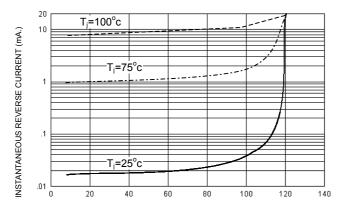
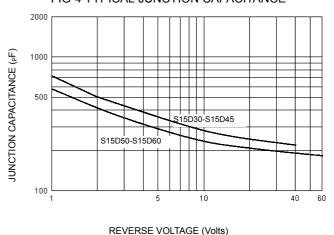
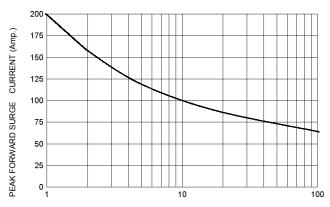


FIG-4 TYPICAL JUNCTION CAPACITANCE



PERCENT OF RATED REVERSE VOLTAGE (%)

FIG-5 PEAK FORWARD SURGE CURRENT



NUMBER OF CYCLES AT 60 Hz